

# BLC10G20LS-240PWT

Power LDMOS transistor

Rev. 1 — 20 April 2017

AMPLEON

Product data sheet

## 1. Product profile

### 1.1 General description

240 W LDMOS power transistor with enhanced video bandwidth for base station applications at frequencies from 1805 MHz to 1995 MHz.

**Table 1. Typical performance**

*Typical RF performance at  $T_{case} = 25\text{ °C}$  in a common source class-AB production test circuit.*

| Test signal      | f            | $I_{DQ}$ | $V_{DS}$ | $P_{L(AV)}$ | $G_p$ | $\eta_D$ | $RL_{in}$ | $ACPR_{5M}$             |
|------------------|--------------|----------|----------|-------------|-------|----------|-----------|-------------------------|
|                  | (MHz)        | (mA)     | (V)      | (W)         | (dB)  | (%)      | (dB)      | (dBc)                   |
| 2-carrier W-CDMA | 1805 to 1880 | 1600     | 28       | 60          | 19.3  | 30       | -16       | -32 <a href="#">[1]</a> |

[1] Test signal: 3GPP test model 1; 64 DPCH; PAR = 8.4 dB at 0.01 % probability on CCDF per carrier; 5 MHz carrier spacing.

### 1.2 Features and benefits

- Excellent ruggedness
- Excellent video bandwidth enabling full band operation
- High efficiency
- Low thermal resistance providing excellent thermal stability
- Designed for low memory effects providing excellent pre-distortability
- Device can operate with the supply current delivered through the video leads
- Internally matched for ease of use
- Integrated ESD protection
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

### 1.3 Applications

- RF power amplifiers for base stations and multi carrier applications in the 1805 MHz to 1995 MHz frequency range

## 2. Pinning information

Table 2. Pinning

| Pin | Description                          | Simplified outline | Graphic symbol |
|-----|--------------------------------------|--------------------|----------------|
| 1   | drain1                               |                    |                |
| 2   | drain2                               |                    |                |
| 3   | gate1                                |                    |                |
| 4   | gate2                                |                    |                |
| 5   | video decoupling <a href="#">[1]</a> |                    |                |
| 6   | video decoupling <a href="#">[1]</a> |                    |                |
| 7   | source <a href="#">[2]</a>           |                    |                |

[1] Device can operate with the supply current delivered through the combined video decoupling leads.

[2] Connected to flange.

## 3. Ordering information

Table 3. Ordering information

| Type number       | Package |   |           |
|-------------------|---------|---|-----------|
|                   | Name    | Description   | Version   |
| BLC10G20LS-240PWT | -       | air cavity plastic earless flanged package; 6 leads | SOT1275-1 |

## 4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol    | Parameter                                | Conditions | Min | Max  | Unit |
|-----------|--|------------|-----|------|------|
| $V_{DS}$  | drain-source voltage                     |            | -   | 65   | V    |
| $V_{GS}$  | gate-source voltage                      |            | -6  | +13  | V    |
| $T_{stg}$ | storage temperature                      |            | -65 | +150 | °C   |
| $T_j$     | junction temperature <a href="#">[1]</a> |            | -   | 225  | °C   |

[1] Continuous use at maximum temperature will affect the reliability, for details refer to the online MTF calculator.

## 5. Thermal characteristics

Table 5. Thermal characteristics

| Symbol        | Parameter                                | Conditions                                   | Typ  | Unit |
|---------------|--|--|------|------|
| $R_{th(j-c)}$ | thermal resistance from junction to case | $T_{case} = 80\text{ °C}; P_L = 60\text{ W}$ | 0.34 | K/W  |

## 6. Characteristics

**Table 6. DC characteristics**

$T_j = 25\text{ °C}$  per section, unless otherwise specified.

| Symbol        | Parameter                        | Conditions  | Min | Typ | Max | Unit          |
|---------------|----------------------------------|---|-----|-----|-----|---------------|
| $V_{(BR)DSS}$ | drain-source breakdown voltage   | $V_{GS} = 0\text{ V}; I_D = 1.49\text{ mA}$                 | 65  | -   | -   | V             |
| $V_{GS(th)}$  | gate-source threshold voltage    | $V_{DS} = 10\text{ V}; I_D = 149\text{ mA}$                 | 1.5 | 2.5 | -   | V             |
| $V_{GSq}$     | gate-source quiescent voltage    | $V_{DS} = 28\text{ V}; I_D = 800\text{ mA}$                 | 1.7 | 2.2 | 2.7 | V             |
| $I_{DSS}$     | drain leakage current            | $V_{GS} = 0\text{ V}; V_{DS} = 32\text{ V}$                 | -   | -   | 1.4 | $\mu\text{A}$ |
| $I_{DSX}$     | drain cut-off current            | $V_{GS} = V_{GS(th)} + 2.37\text{ V}; V_{DS} = 10\text{ V}$ | -   | 27  | -   | A             |
| $I_{GSS}$     | gate leakage current             | $V_{GS} = 9\text{ V}; V_{DS} = 0\text{ V}$                  | -   | -   | 140 | nA            |
| $g_{fs}$      | forward transconductance         | $V_{DS} = 10\text{ V}; I_D = 7.45\text{ A}$                 | -   | 16  | -   | S             |
| $R_{DS(on)}$  | drain-source on-state resistance | $V_{GS} = V_{GS(th)} + 2.37\text{ V}; I_D = 5.2\text{ A}$   | -   | 0.1 | -   | $\Omega$      |

**Table 7. RF characteristics**

Test signal: 2-carrier W-CDMA; 3GPP test model 1 with 64 DPCH; PAR = 8.4 dB at 0.01 % probability on the CCDF;  $f_1 = 1807.5\text{ MHz}; f_2 = 1812.5\text{ MHz}; f_3 = 1872.5\text{ MHz}; f_4 = 1877.5\text{ MHz}$ ; RF performance at  $V_{DS} = 28\text{ V}; I_{Dq} = 1600\text{ mA}; T_{case} = 25\text{ °C}$ ; unless otherwise specified; in a water cooled class-AB test circuit.

| Symbol      | Parameter                            | Conditions                | Min  | Typ  | Max | Unit |
|-------------|--------------------------------------|---------------------------|------|------|-----|------|
| $G_p$       | power gain                           | $P_{L(AV)} = 60\text{ W}$ | 18.3 | 19.3 | -   | dB   |
| $\eta_D$    | drain efficiency                     | $P_{L(AV)} = 60\text{ W}$ | 26.5 | 30   | -   | %    |
| $RL_{in}$   | input return loss                    | $P_{L(AV)} = 60\text{ W}$ | -    | -16  | -11 | dB   |
| $ACPR_{5M}$ | adjacent channel power ratio (5 MHz) | $P_{L(AV)} = 60\text{ W}$ | -    | -32  | -28 | dBc  |

## 7. Test information

### 7.1 Ruggedness in class-AB operation

The BLC10G20LS-240PWT is capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions:  $V_{DS} = 28\text{ V}; I_{Dq} = 1600\text{ mA}$ ; 2-carrier W-CDMA signal;  $P_L = 120\text{ W}$  average;  $f_c = 1805\text{ MHz}$ ; 5 MHz spacing; 46 % clipping.

## 7.2 Impedance information

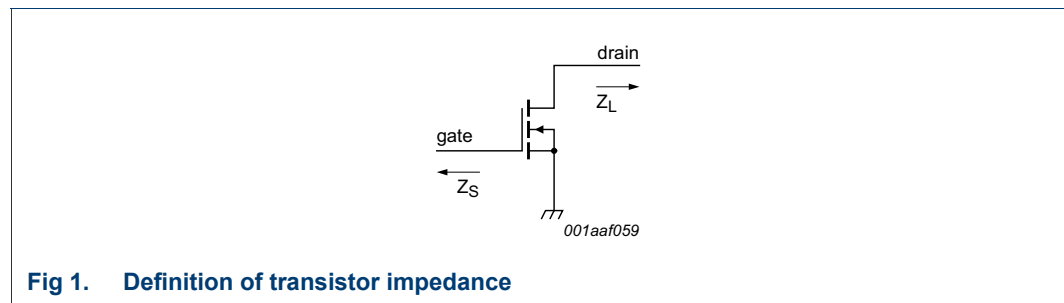
**Table 8. Typical impedance**

Measured load-pull data per section;  $I_{Dq} = 800 \text{ mA}$ ;  $V_{DS} = 28 \text{ V}$ ; pulsed CW ( $t_p = 100 \mu\text{s}$ ;  $\delta = 10 \%$ ).

| f<br>(MHz)                           | $Z_S$ [1]<br>( $\Omega$ ) | $Z_L$ [1]<br>( $\Omega$ ) | $P_L$ [2]<br>(W) | $\eta_D$ [2]<br>(%) | $G_p$ [2]<br>(dB) |
|--------------------------------------|---------------------------|---------------------------|------------------|---------------------|-------------------|
| <b>Maximum power load</b>            |                           |                           |                  |                     |                   |
| 1805                                 | 3.0 – j9.0                | 2.2 – j6.9                | 213.8            | 62.3                | 16.1              |
| 1840                                 | 3.6 – j9.6                | 2.2 – j7.1                | 213.4            | 61.8                | 16.2              |
| 1880                                 | 4.0 – j10.0               | 2.3 – j7.2                | 211.9            | 62.2                | 16.4              |
| 1930                                 | 6.4 – j10.5               | 2.3 – j7.2                | 208.5            | 62.3                | 16.6              |
| 1960                                 | 7.0 – j11.0               | 2.1 – j7.1                | 206.6            | 60.3                | 16.5              |
| 1990                                 | 9.0 – j10.3               | 2.3 – j7.2                | 203.8            | 62.2                | 16.9              |
| <b>Maximum drain efficiency load</b> |                           |                           |                  |                     |                   |
| 1805                                 | 3.0 – j9.0                | 4.6 – j6.8                | 162.2            | 70.4                | 18.1              |
| 1840                                 | 3.6 – j9.6                | 4.1 – j6.2                | 164.7            | 70.2                | 18.2              |
| 1880                                 | 4.0 – j10.0               | 3.8 – j6.3                | 161.6            | 69.9                | 18.3              |
| 1930                                 | 6.4 – j10.5               | 3.6 – j5.9                | 159.1            | 69.3                | 18.4              |
| 1960                                 | 7.0 – j11.0               | 3.6 – j5.8                | 157.1            | 68.6                | 18.5              |
| 1990                                 | 9.0 – j10.3               | 3.2 – j5.7                | 154.4            | 68.3                | 18.6              |

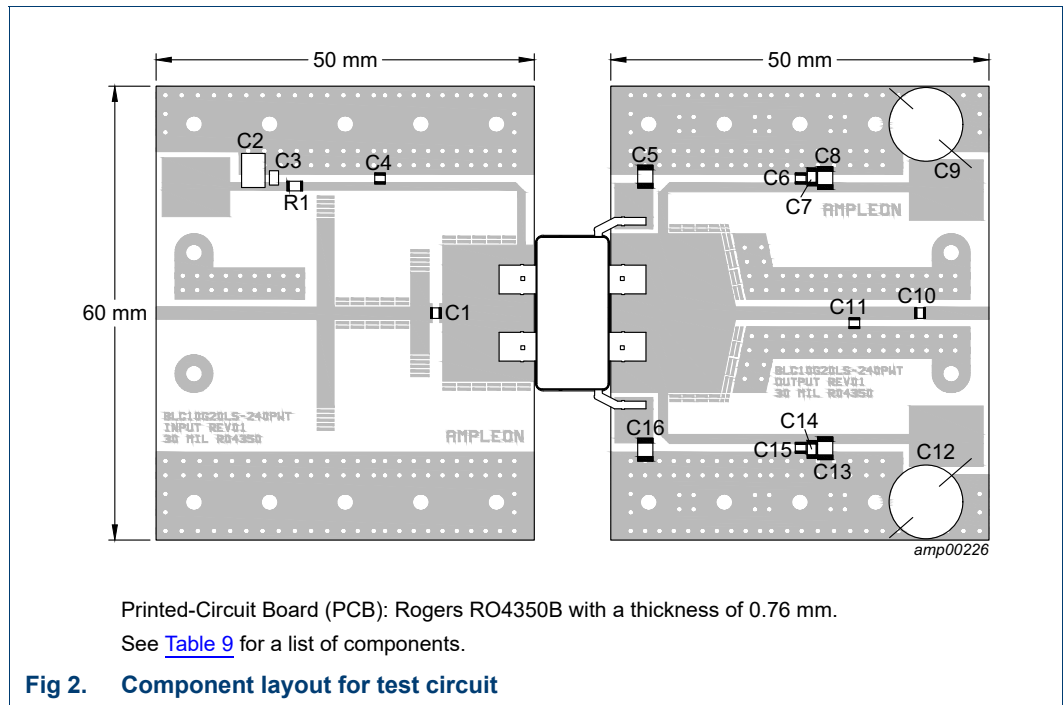
[1]  $Z_S$  and  $Z_L$  defined in [Figure 1](#).

[2] at 3 dB gain compression.



**Fig 1. Definition of transistor impedance**

7.3 Test circuit



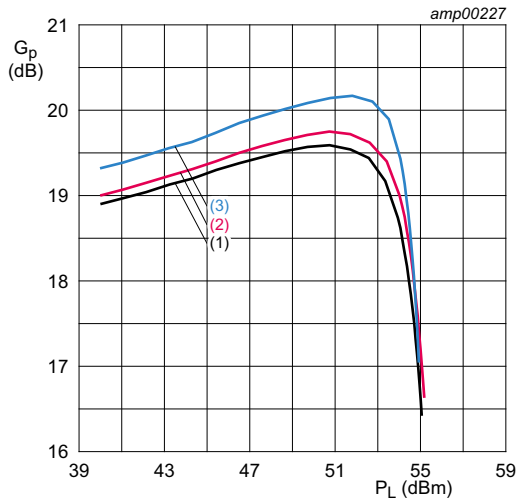
**Table 9. List of components**

See [Figure 2](#) for component layout.

| Component        | Description                       | Value                | Remarks  |
|------------------|-----------------------------------|----------------------|----------|
| C1               | multilayer ceramic chip capacitor | 1.5 pF               | ATC 800A |
| C2               | multilayer ceramic chip capacitor | 1 μF                 | Murata   |
| C3               | multilayer ceramic chip capacitor | 100 nF               | Murata   |
| C4, C6, C10, C15 | multilayer ceramic chip capacitor | 43 pF                | ATC 800A |
| C5, C8, C13, C16 | multilayer ceramic chip capacitor | 4.7 μF, 100 V        | Murata   |
| C7, C14          | multilayer ceramic chip capacitor | 220 nF               | Murata   |
| C9, C12          | electrolytic capacitor            | > 470 μF, 63 V       | low ESR  |
| C11              | multilayer ceramic chip capacitor | 1.2 pF               | ATC 800A |
| R1               | resistor                          | 4.7 Ω, 1 % tolerance | SMD 0805 |

7.4 Graphical data

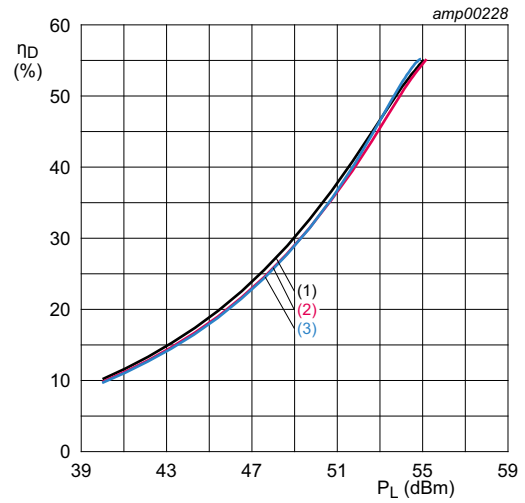
7.4.1 Pulsed CW



$V_{DS} = 28\text{ V}; I_{Dq} = 1600\text{ mA}; t_p = 100\text{ }\mu\text{s}; \delta = 10\text{ }\%$ .

- (1)  $f = 1805\text{ MHz}$
- (2)  $f = 1840\text{ MHz}$
- (3)  $f = 1880\text{ MHz}$

**Fig 3. Power gain as a function of output power; typical values**

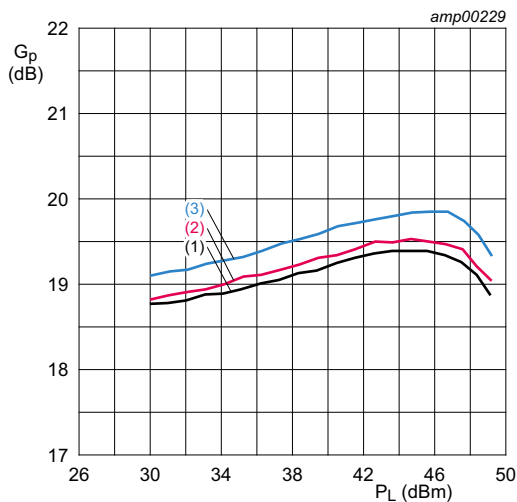


$V_{DS} = 28\text{ V}; I_{Dq} = 1600\text{ mA}; t_p = 100\text{ }\mu\text{s}; \delta = 10\text{ }\%$ .

- (1)  $f = 1805\text{ MHz}$
- (2)  $f = 1840\text{ MHz}$
- (3)  $f = 1880\text{ MHz}$

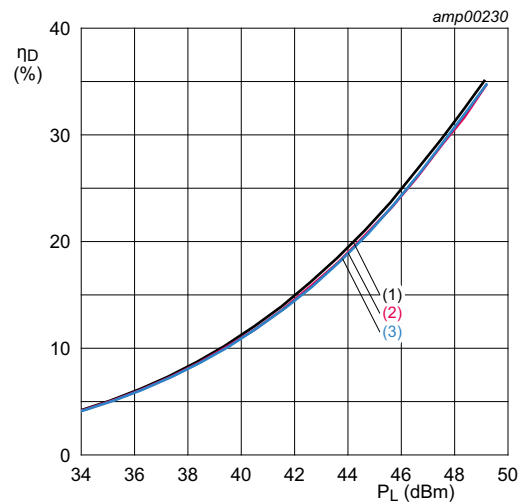
**Fig 4. Drain efficiency as a function of output power; typical values**

7.4.2 IS-95



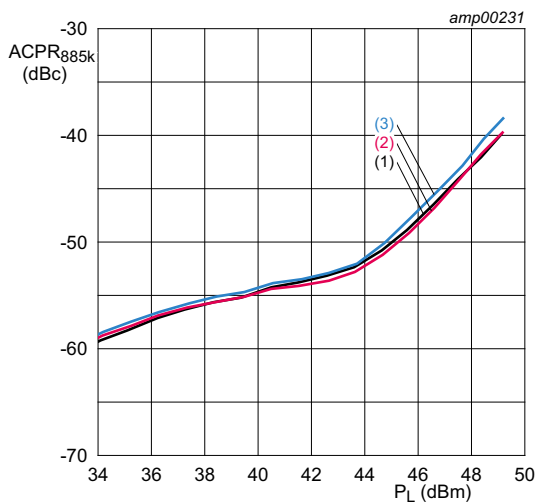
$V_{DS} = 28\text{ V}; I_{Dq} = 1600\text{ mA}.$   
 (1)  $f = 1810\text{ MHz}$   
 (2)  $f = 1840\text{ MHz}$   
 (3)  $f = 1875\text{ MHz}$

**Fig 5. Power gain as a function of output power; typical values**



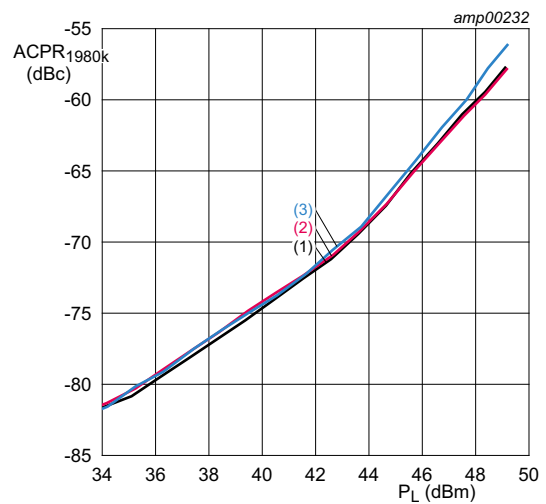
$V_{DS} = 28\text{ V}; I_{Dq} = 1600\text{ mA}.$   
 (1)  $f = 1810\text{ MHz}$   
 (2)  $f = 1840\text{ MHz}$   
 (3)  $f = 1875\text{ MHz}$

**Fig 6. Drain efficiency as a function of output power; typical values**



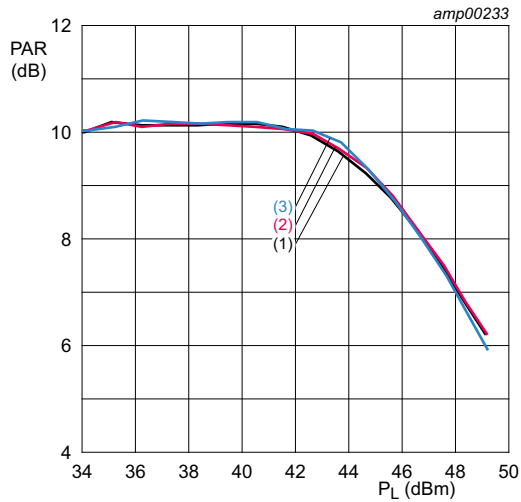
$V_{DS} = 28\text{ V}; I_{Dq} = 1600\text{ mA}.$   
 (1)  $f = 1810\text{ MHz}$   
 (2)  $f = 1840\text{ MHz}$   
 (3)  $f = 1875\text{ MHz}$

**Fig 7. Adjacent channel power ratio (885 kHz) as a function of output power; typical values**



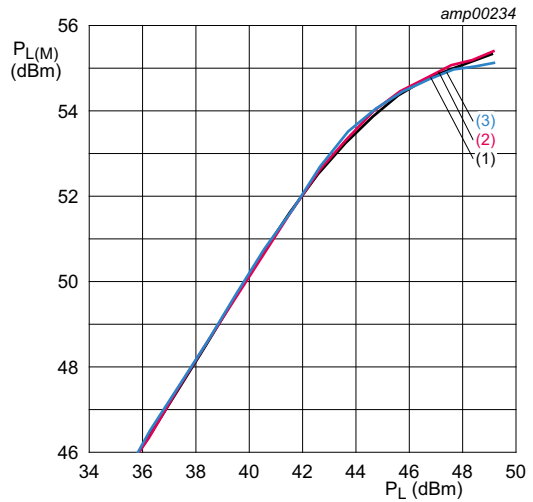
$V_{DS} = 28\text{ V}; I_{Dq} = 1600\text{ mA}.$   
 (1)  $f = 1810\text{ MHz}$   
 (2)  $f = 1840\text{ MHz}$   
 (3)  $f = 1875\text{ MHz}$

**Fig 8. Adjacent channel power ratio (1980 kHz) as a function of output power; typical values**



$V_{DS} = 28\text{ V}; I_{Dq} = 1600\text{ mA}.$   
 (1)  $f = 1810\text{ MHz}$   
 (2)  $f = 1840\text{ MHz}$   
 (3)  $f = 1875\text{ MHz}$

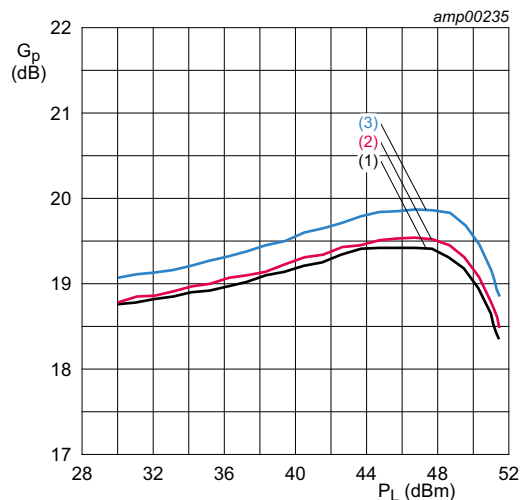
**Fig 9. Peak-to-average ratio as a function of output power; typical values**



$V_{DS} = 28\text{ V}; I_{Dq} = 1600\text{ mA}.$   
 (1)  $f = 1810\text{ MHz}$   
 (2)  $f = 1840\text{ MHz}$   
 (3)  $f = 1875\text{ MHz}$

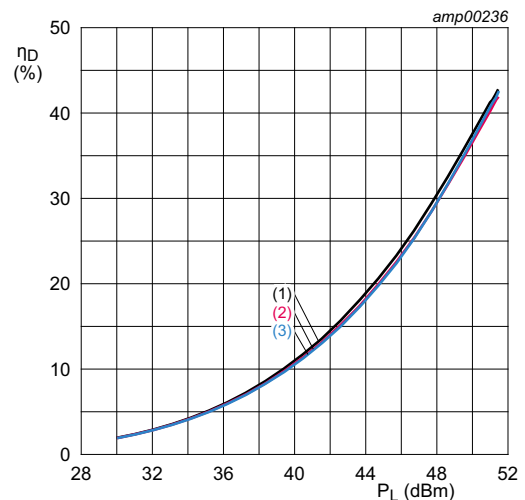
**Fig 10. Peak output power as a function of output power; typical values**

7.4.3 1-Carrier W-CDMA



$V_{DS} = 28\text{ V}; I_{Dq} = 1600\text{ mA}.$   
 (1)  $f = 1807.5\text{ MHz}$   
 (2)  $f = 1840\text{ MHz}$   
 (3)  $f = 1877.5\text{ MHz}$

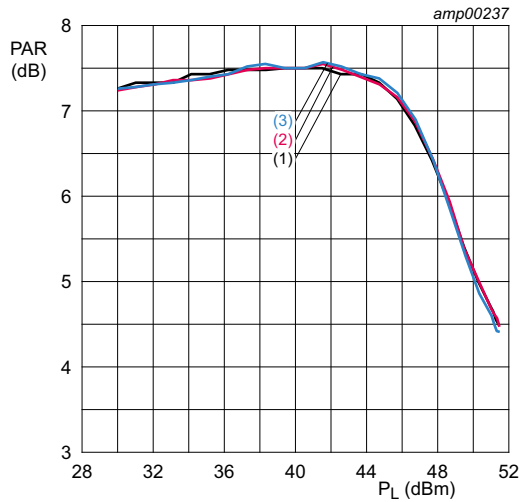
**Fig 11. Power gain as a function of output power; typical values**



$V_{DS} = 28\text{ V}; I_{Dq} = 1600\text{ mA}.$   
 (1)  $f = 1807.5\text{ MHz}$   
 (2)  $f = 1840\text{ MHz}$   
 (3)  $f = 1877.5\text{ MHz}$

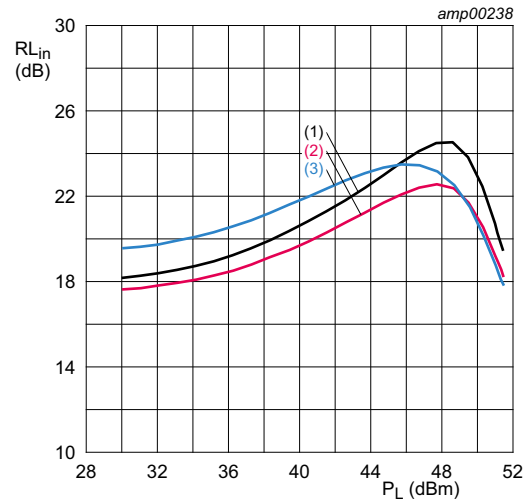
**Fig 12. Drain efficiency as a function of output power; typical values**





$V_{DS} = 28\text{ V}; I_{Dq} = 1600\text{ mA}.$   
 (1)  $f = 1807.5\text{ MHz}$   
 (2)  $f = 1840\text{ MHz}$   
 (3)  $f = 1877.5\text{ MHz}$

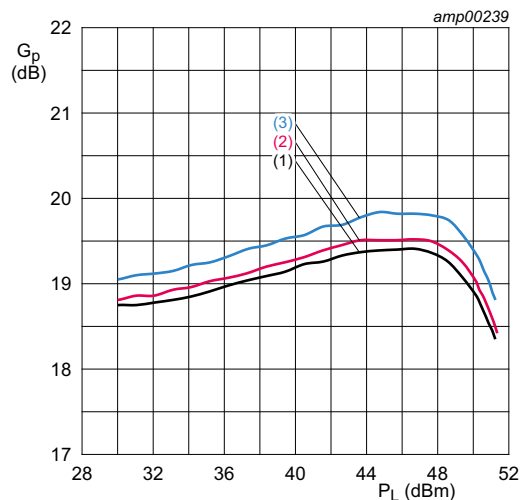
**Fig 13. Peak-to-average ratio as a function of output power; typical values**



$V_{DS} = 28\text{ V}; I_{Dq} = 1600\text{ mA}.$   
 (1)  $f = 1807.5\text{ MHz}$   
 (2)  $f = 1840\text{ MHz}$   
 (3)  $f = 1877.5\text{ MHz}$

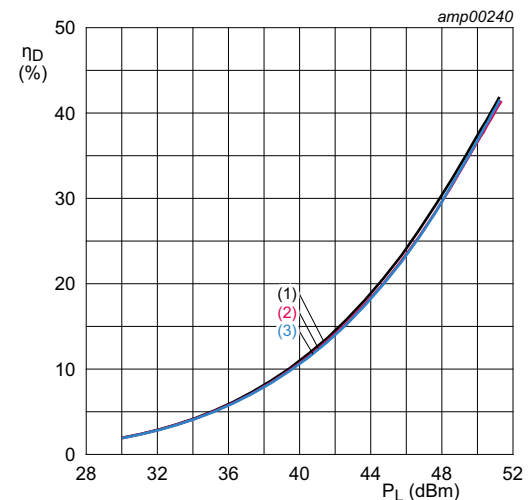
**Fig 14. Input return loss as a function of output power; typical values**

**7.4.4 2-Carrier W-CDMA**



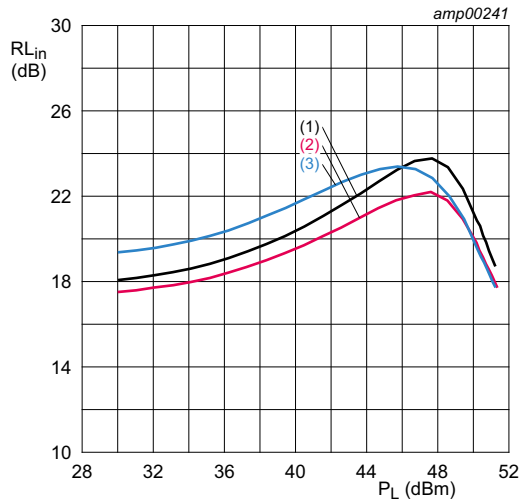
$V_{DS} = 28\text{ V}; I_{Dq} = 1600\text{ mA}.$   
 (1)  $f = 1810\text{ MHz}$   
 (2)  $f = 1840\text{ MHz}$   
 (3)  $f = 1875\text{ MHz}$

**Fig 15. Power gain as a function of output power; typical values**



$V_{DS} = 28\text{ V}; I_{Dq} = 1600\text{ mA}.$   
 (1)  $f = 1810\text{ MHz}$   
 (2)  $f = 1840\text{ MHz}$   
 (3)  $f = 1875\text{ MHz}$

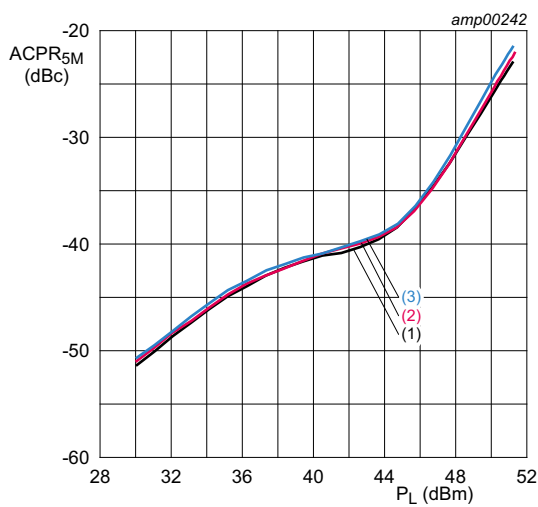
**Fig 16. Drain efficiency as a function of output power; typical values**



$V_{DS} = 28\text{ V}; I_{Dq} = 1600\text{ mA.}$

- (1)  $f = 1810\text{ MHz}$
- (2)  $f = 1840\text{ MHz}$
- (3)  $f = 1875\text{ MHz}$

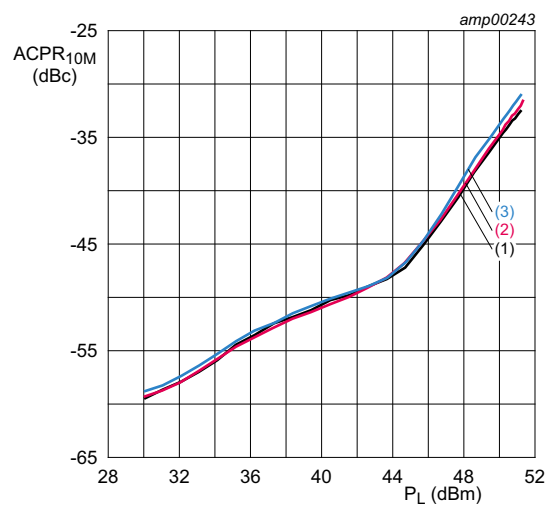
**Fig 17. Input return loss as a function of output power; typical values**



$V_{DS} = 28\text{ V}; I_{Dq} = 1600\text{ mA.}$

- (1)  $f = 1810\text{ MHz}$
- (2)  $f = 1840\text{ MHz}$
- (3)  $f = 1875\text{ MHz}$

**Fig 18. Adjacent channel power ratio (5 MHz) as a function of output power; typical values**

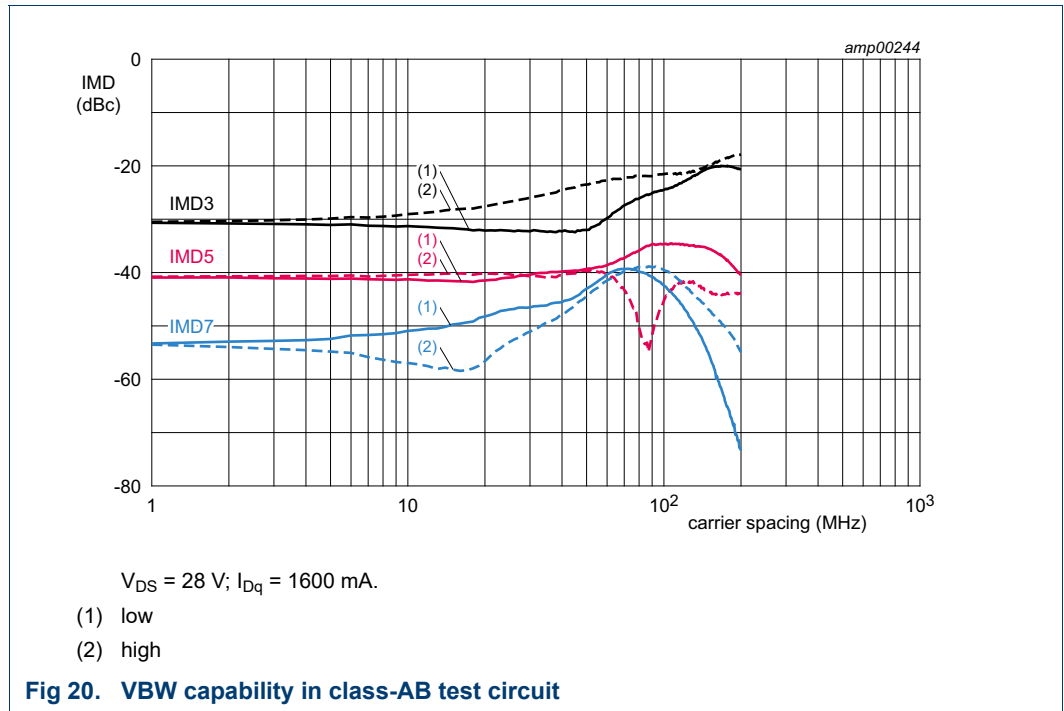


$V_{DS} = 28\text{ V}; I_{Dq} = 1600\text{ mA.}$

- (1)  $f = 1810\text{ MHz}$
- (2)  $f = 1840\text{ MHz}$
- (3)  $f = 1875\text{ MHz}$

**Fig 19. Adjacent channel power ratio (10 MHz) as a function of output power; typical values**

7.4.5 2-Tone VBW



### 8. Package outline

Air cavity plastic earless flanged package; 6 leads

SOT1275-1

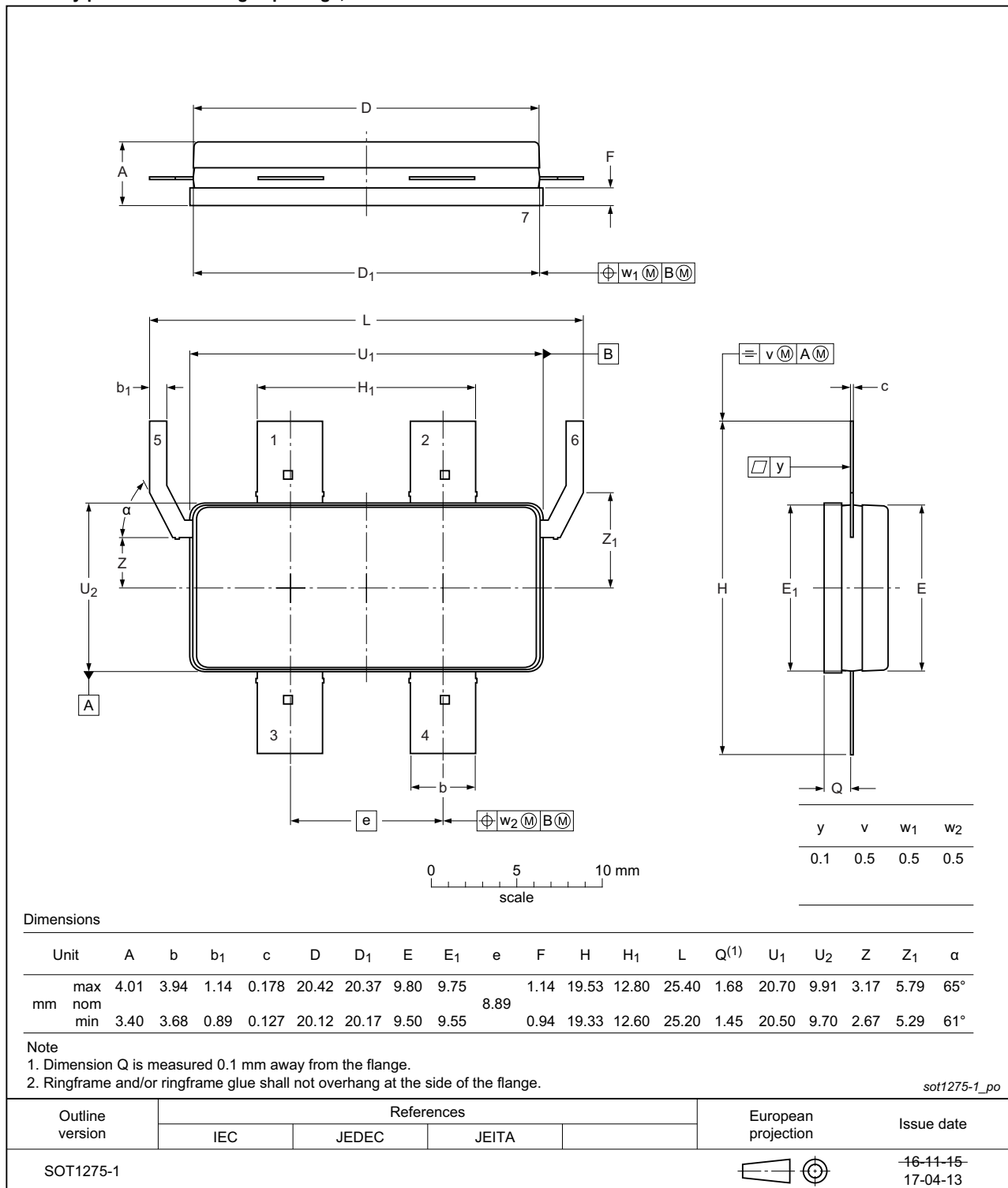


Fig 21. Package outline SOT1275-1

## 9. Handling information

**CAUTION**



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the *ANSI/ESD S20.20*, *IEC/ST 61340-5*, *JESD625-A* or equivalent standards.

**Table 10. ESD sensitivity**

| ESD model  | Class                   |
|--|-------------------------|
| Charged Device Model (CDM); According to ANSI/ESDA/JEDEC standard JS-002 | C2A <a href="#">[1]</a> |
| Human Body Model (HBM); According to ANSI/ESDA/JEDEC standard JS-001     | 2 <a href="#">[2]</a>   |

[1] CDM classification C2A is granted to any part that passes after exposure to an ESD pulse of 500 V, but fails after exposure to an ESD pulse of 750 V.

[2] HBM classification 2 is granted to any part that passes after exposure to an ESD pulse of 2000 V, but fails after exposure to an ESD pulse of 4000 V.

## 10. Abbreviations

**Table 11. Abbreviations**

| Acronym | Description                                    |
|---------|--|
| 3GPP    | 3rd Generation Partnership Project             |
| CCDF    | Complementary Cumulative Distribution Function |
| CW      | Continuous Wave                                |
| DPCH    | Dedicated Physical CHannel                     |
| ESD     | ElectroStatic Discharge                        |
| LDMOS   | Laterally Diffused Metal Oxide Semiconductor   |
| MTF     | Median Time to Failure                         |
| PAR     | Peak-to-Average Ratio                          |
| SMD     | Surface Mounted Device                         |
| VSWR    | Voltage Standing Wave Ratio                    |
| W-CDMA  | Wideband Code Division Multiple Access         |

## 11. Revision history

**Table 12. Revision history**

| Document ID           | Release date | Data sheet status  | Change notice | Supersedes |
|-----------------------|--------------|--------------------|---------------|------------|
| BLC10G20LS-240PWT v.1 | 20170420     | Product data sheet | -             | -          |

## 12. Legal information

### 12.1 Data sheet status

| Document status <sup>[1][2]</sup> | Product status <sup>[3]</sup> | Definition  |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet      | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet    | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet        | Production                    | This document contains the product specification.                                     |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.ampleon.com>.

### 12.2 Definitions

**Draft** — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Ampleon does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

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## 13. Contact information

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